# **74AUP1G08**

# Low-power 2-input AND gate

Rev. 9 — 5 August 2021

**Product data sheet** 

### 1. General description

The 74AUP1G08 is a single 2-input AND gate. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

#### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- · Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- · Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package	Package							
	Temperature range	Name	Description	Version					
74AUP1G08GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1					
74AUP1G08GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886					
74AUP1G08GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115					
74AUP1G08GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202					
74AUP1G08GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3					

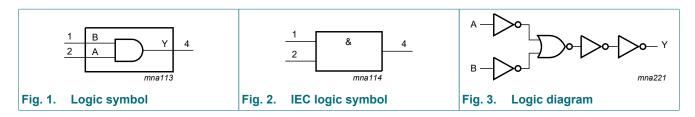
# 4. Marking

Table 2. Marking

<u> </u>				
Type number	Marking code[1]			
74AUP1G08GW	pE			
74AUP1G08GM	pE			
74AUP1G08GN	pE			
74AUP1G08GS	pE			
74AUP1G08GX	pE			

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

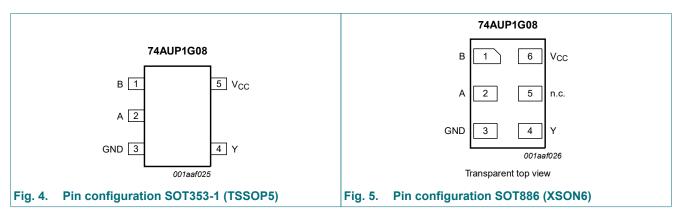
# 5. Functional diagram



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# 6. Pinning information

### 6.1. Pinning





# 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin		
	TSSOP5 and X2SON5	XSON6		
В	1	1	data input	
A	2	2	data input	
GND	3	3	ground (0 V)	
Υ	4	4	data output	
n.c.	-	5	not connected	
V <sub>CC</sub>	5	6	supply voltage	

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# 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input		Output
A	В	Υ
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
lok	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
I <sub>CC</sub>	supply current			-	+50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	250	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

<sup>[2]</sup> For SOT353-1 (TSSOP5) package: P<sub>tot</sub> derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: P<sub>tot</sub> derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package:  $P_{tot}$  derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: Ptot derates linearly with 3.0 mW/K above 67 °C.

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# 10. Static characteristics

**Table 7. Static characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	$I_O = -20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_{I}$ = GND or $V_{CC}$	-	8.0	-	pF
Co	output capacitance	V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.7	-	pF

# Low-power 2-input AND gate

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μA
l <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	μΑ
I <sub>CC</sub>	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μΑ
T <sub>amb</sub> = -	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.75 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.25 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	_	-	0.9	V

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### Low-power 2-input AND gate

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1.4	μΑ
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V} $ [1]	-	-	75	μΑ

<sup>[1]</sup> One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

# 11. Dynamic characteristics

**Table 8. Dynamic characteristics** 

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9

Symbol	Parameter	Conditions		Min	Typ [1]	Max	Unit
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 5 pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 8	2]				
		V <sub>CC</sub> = 0.8 V		-	17.0	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		2.6	5.1	10.8	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		1.6	3.7	6.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.3	3.0	5.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		1.1	2.4	4.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		1.0	2.2	3.5	ns

### Low-power 2-input AND gate

Symbol	Parameter	Conditions		Min	Typ [1]	Max	Unit
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 10 pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 8	[2]				
		V <sub>CC</sub> = 0.8 V		-	20.6	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		2.4	6.0	12.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		2.0	4.3	7.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.7	3.6	6.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		1.4	2.9	4.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		1.3	2.7	4.2	ns
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 15 pF	·					
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 8	[2]				
		V <sub>CC</sub> = 0.8 V		-	24.1	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		3.4	6.8	14.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		2.3	4.9	8.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.9	4.0	6.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		1.7	3.4	5.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		1.5	3.1	4.8	ns
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 30 pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see Fig. 8	[2]				
		V <sub>CC</sub> = 0.8 V		-	34.4	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		4.6	9.1	19.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		3.4	6.4	11.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.6	5.3	9.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		2.3	4.5	7.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		2.2	4.2	6.2	ns
T <sub>amb</sub> = 2	5 °C						
C <sub>PD</sub>	power dissipation	$f = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}$	[3]				
	capacitance	V <sub>CC</sub> = 0.8 V		-	2.5	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V		-	2.7	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V		-	2.8	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V		-	2.9	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V		-	3.5	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V		-	4.0	-	pF
	1						

<sup>[1]</sup> All typical values are measured at nominal  $V_{CC}$ .

 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

 <sup>[2]</sup> t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
 [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).
 P<sub>D</sub> = C<sub>PD</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>i</sub> x N + Σ(C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) where:

### Low-power 2-input AND gate

**Table 9. Dynamic characteristics** 

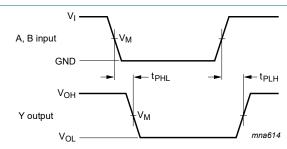
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9

Symbol	Parameter	Conditions	-40 °C 1	to +85 °C	-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.1	11.7	2.1	12.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.5	7.5	1.5	8.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.3	6.1	1.3	6.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	4.8	1.0	5.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.9	4.3	0.9	4.8	ns
C <sub>L</sub> = 10	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.2	13.6	2.2	15.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.8	8.9	1.8	9.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.6	7.2	1.6	7.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.3	5.7	1.3	6.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.2	4.7	1.2	5.2	ns
C <sub>L</sub> = 15	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.1	15.7	3.1	17.3	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	10.1	2.1	11.2	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.8	8.2	1.8	9.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	6.5	1.6	7.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	5.9	1.5	6.5	ns
C <sub>L</sub> = 30	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.1	21.8	4.1	24.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.9	13.6	2.9	15.0	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.4	10.9	2.4	12.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.2	8.6	2.2	9.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	7.5	2.1	8.3	ns

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

Low-power 2-input AND gate

#### 11.1. Waveforms and test circuit



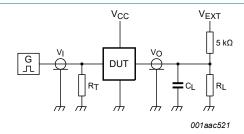
Measurement points are given in Table 10.

Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

Fig. 8. The data input (A or B) to output (Y) propagation delays

**Table 10. Measurement points** 

Supply voltage	Output	Input					
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>I</sub>	$t_r = t_f$			
0.8 V to 3.6 V	0.5 x V <sub>CC</sub>	0.5 x V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns			



Test data is given in Table 11.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

Fig. 9. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V <sub>EXT</sub>			
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>	
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 x V <sub>CC</sub>	

[1] For measuring enable and disable times  $R_L$  = 5  $k\Omega.$ 

For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1  $M\Omega$ .

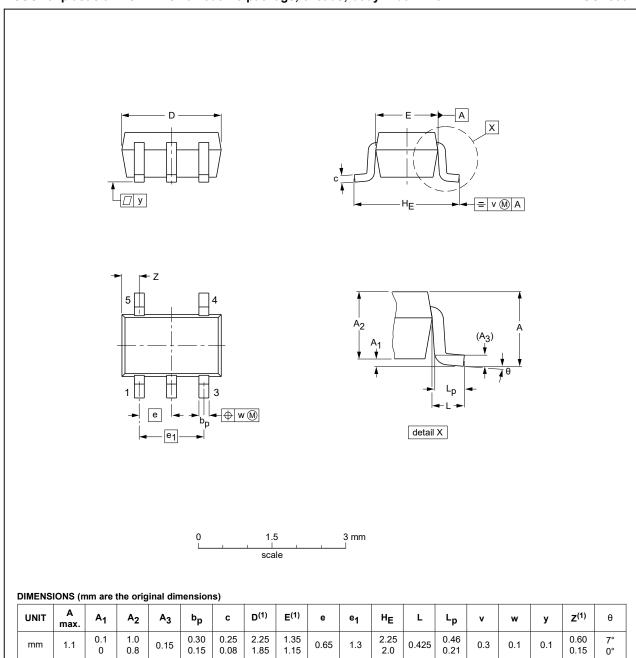
**Product data sheet** 

Low-power 2-input AND gate

# 12. Package outline

#### TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



U	JNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	HE	L	Lp	v	w	у	Z <sup>(1)</sup>	θ
r	mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A			<del>-00-09-01</del> 03-02-19

Fig. 10. Package outline SOT353-1 (TSSOP5)

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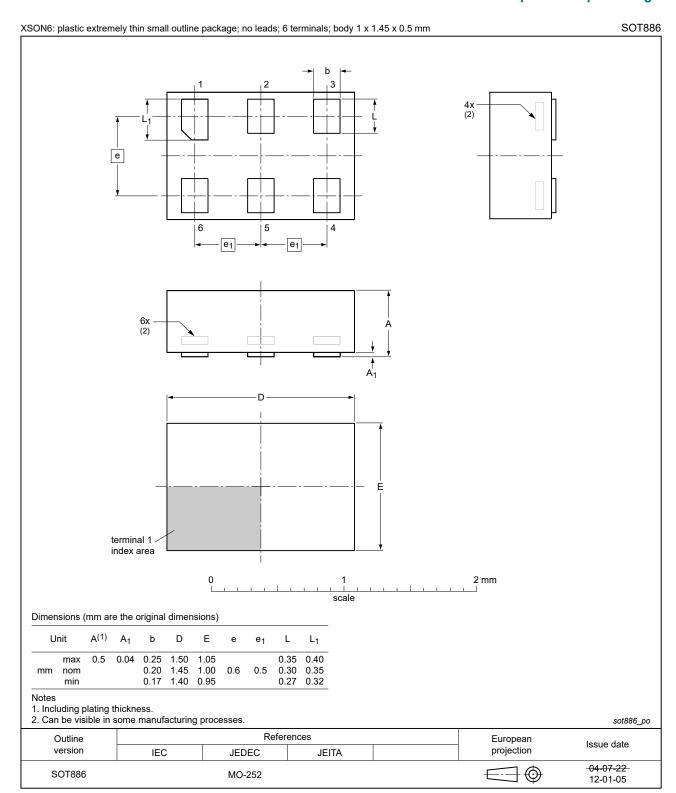


Fig. 11. Package outline SOT886 (XSON6)

**Product data sheet** 

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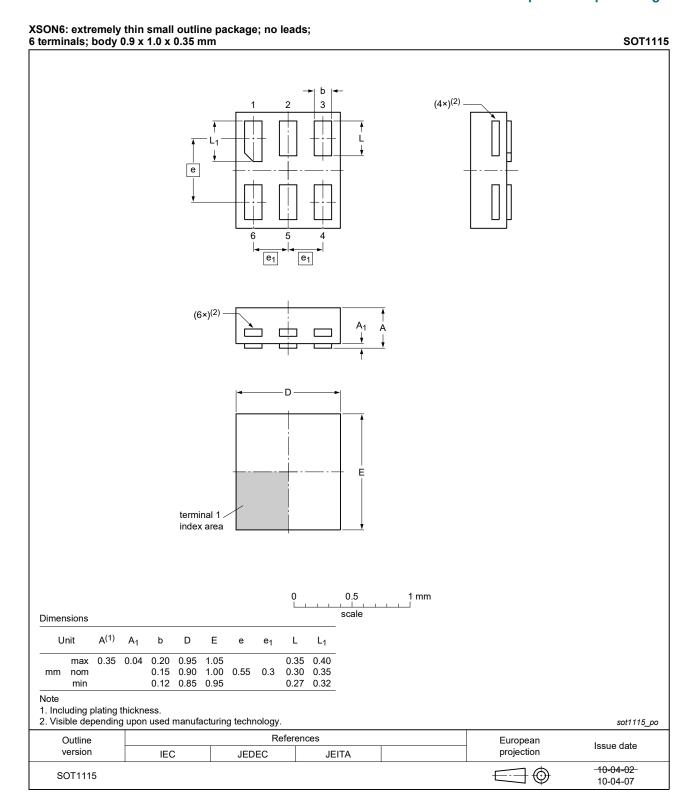


Fig. 12. Package outline SOT1115 (XSON6)

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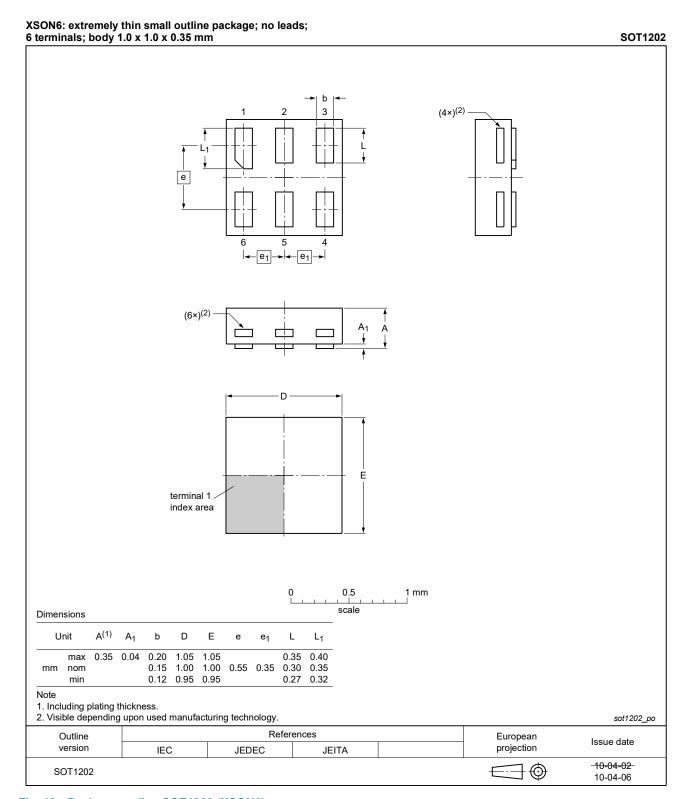


Fig. 13. Package outline SOT1202 (XSON6)

Low-power 2-input AND gate

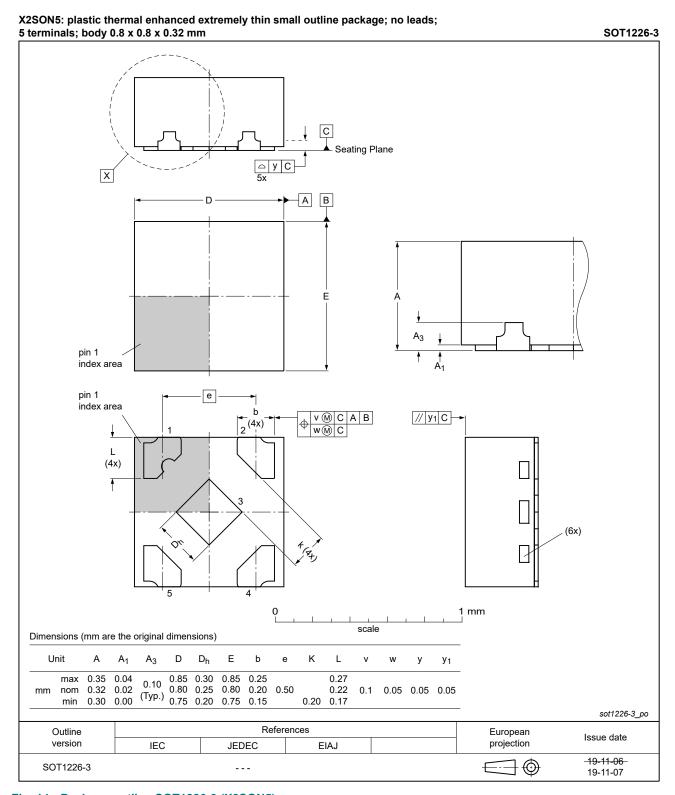


Fig. 14. Package outline SOT1226-3 (X2SON5)

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Low-power 2-input AND gate

# 13. Abbreviations

#### **Table 12. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

#### **Table 13. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes						
74AUP1G08 v.9	20210805	Product data sheet	-	74AUP1G08 v.8						
Modifications:		<ul> <li><u>Section 1</u> and <u>Section 2</u> updated.</li> <li>Type number 74AUP1G08GF (SOT891/XSON6) removed.</li> </ul>								
74AUP1G08 v.8	20210421	Product data sheet	-	74AUP1G08 v.7						
Modifications:	,	<ul> <li>SOT1226 (X2SON5) package changed to SOT1226-3 (X2SON5) package.</li> <li>Table 5: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>								
74AUP1G08 v.7	20171130	Product data sheet	-	74AUP1G08 v.6						
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>									
74AUP1G08 v.6	20120622	Product data sheet	-	74AUP1G08 v.5						
Modifications:	Package ou	tline drawing of SOT1226	modified.							
74AUP1G08 v.5	20120412	Product data sheet	-	74AUP1G08 v.4						
Modifications:	<ul> <li>Added type number 74AUP1G08GX (SOT1226)</li> <li>Package outline drawing of SOT886 (Fig. 11) modified.</li> </ul>									
74AUP1G08 v.4	20111115	Product data sheet	-	74AUP1G08 v.3						
Modifications:	Legal pages	updated.								
74AUP1G08 v.3	20101007	Product data sheet	-	74AUP1G08 v.2						
74AUP1G08 v.2	20060629	Product data sheet	-	74AUP1G08 v.1						
74AUP1G08 v.1	20050720	Product data sheet	-	-						

#### Low-power 2-input AND gate

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- Please consult the most recently issued document before initiating or completing a design.
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74AUP1G08

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